APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention

MOSFET PERFORMANCE IMPROVEMENT USING DEFORMATION IN

SOI STRUCTURE

Application Type: regular, utility

Attorney Docket Number: FIS920030185US1

Correspondence address:

Customer Number: 29625

Inventors Information:

Inventor 1:

Applicant Authority Type: Inventor
Citizenship: US

Given Name: Dureseti
Family Name: Chidambarrao

Residence:

City of Residence: Weston
State of Residence: CT
Country of Residence: US

Address-1 of Mailing Address: 29 Old Mill Road

US

Address-2 of Mailing Address:

City of Mailing Address: Weston
State of Mailing Address: CT
Postal Code of Mailing Address: 06883

Country of Mailing Address:

Phone: Fax: F-mail:

Inventor 2:

Applicant Authority Type: Inventor
Citizenship: TR
Given Name: Omer
Middle Name: H.

Family Name: Dukumaci

Residence:	
City of Residence:	Wappingers Falls
State of Residence:	NY
Country of Residence:	US
Address-1 of Mailing Address:	32E Winthrop Court
Address-2 of Mailing Address:	
City of Mailing Address:	Wappingers Falls
State of Mailing Address:	NY
Postal Code of Mailing Address:	12590
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	
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Assignee 1:	
Organization Name:	International Business Machines Corporation
Address-1 of Mailing Address:	New Orchard Road
Address-2 of Mailing Address:	
City of Mailing Address:	Armonk
State of Mailing Address:	NY
Postal Code of Mailing Address:	10504
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	